DATA SHEET

DARLINGTON POWER TRANSISTOR 2SD2217

NPN SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING

The 2SD2217 is a mold power transistor developed for lowfrequency power amplifiers and low-speed switching. This transistor is ideal for direct driving from the IC out to drivers such as pulse motor drivers and relay drivers in OA and FA equipment.

QUALITY GRADES

NEC

Standard

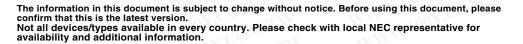
Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	300	V
Collector to emitter voltage	VCEO	300	v
Emitter to base voltage	Vево	7	V
Collector current		300	mA
Collector current	IC(pulse)*	600	mA
Base current	IB(DC)	30	mA
Total power dissipation	P⊤ (Tc = 25°C)	25	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	100 ¹ Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

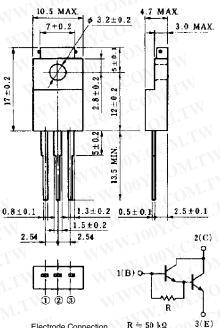
* PW \leq 10 ms, duty cycle \leq 50%

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PACKAGE DRAWING (UNIT: mm)



Electrode Connection

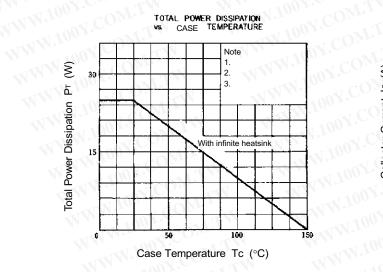
- 1. Base (B)
- 2. Collector (C)
- 3. Emitter (E)

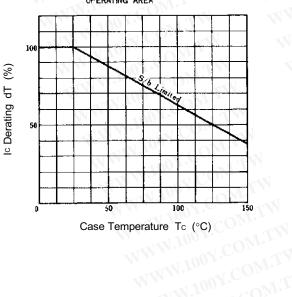
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	ι
Collector cutoff current	Ісво	V _{CB} = 300 V, I _E = 0		U.T.W	10	ļ
Collector cutoff current	ICEO	V _{CE} = 60 V, R _{BE} = ∞	M.C.	M.T.W	10	I
Emitter cutoff current	Іево	V _{EB} = 5 V, Ic = 0	NOY.CO	WT.I.	10	ļ
DC current gain	hFE1**	Vce = 1.5 V, lc = 20 mA	1,000	T	V	
DC current gain	hFE2**	Vce = 1.5 V, lc = 100 mA	1,500	7,000	30,000	
Collector saturation voltage	VCE(sat)**	Ic = 100 mA, I _B = 0.2 mA	1.100	0.8	1.5	
Base saturation voltage	VBE(sat)**	Ic = 100 mA, I _B = 0.2 mA	W.100 .	1.4	2.0	
Gain bandwidth product	fт	Vce = 1.5 V, Ic = 20 mA	W.100	45		N
Collector capacitance	Cob	V _{CB} = 10 V, I _E = 0, f = 1.0 MHz	10	22	N.T.W	ł

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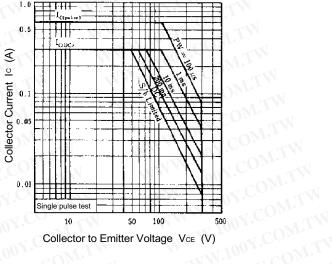
TYPICAL CHARACTERISTICS (Ta = 25°C)



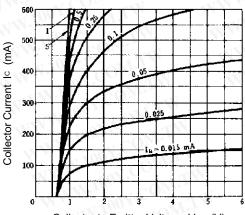


DERATING CURVE OF SAFE OPERATING AREA

FORWARD BIAS SAFE OPFRATING AREA

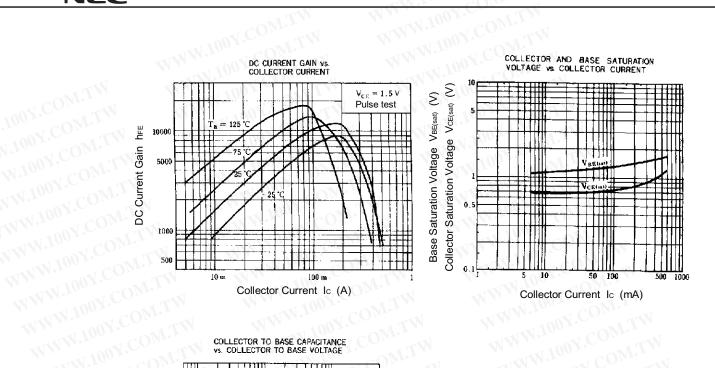


COLLECTOR CURRENT VS. COLLECTOR TO EMITTER VOLTAGE

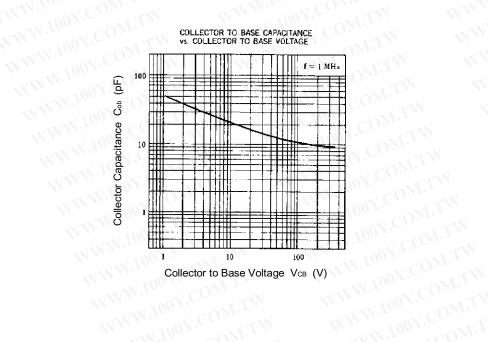


Collector to Emitter Voltage VCE (V)

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- Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster "Special": systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
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